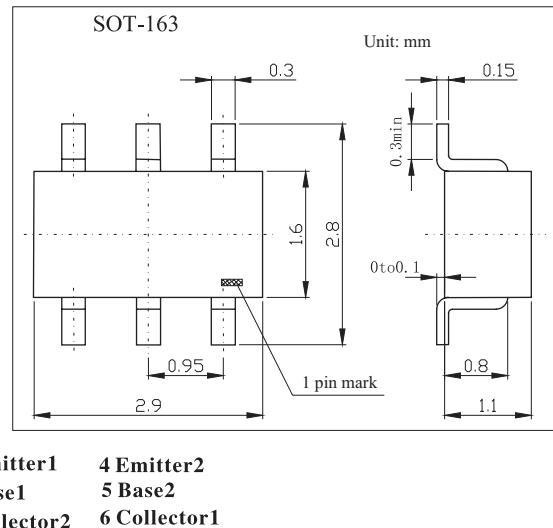
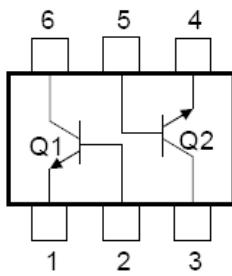


HN1C07F

■ Features

- Excellent Current Gain(hFE)linearity
: $hFE=25$ (min) at $V_{CE}=6V, I_C=400mA$



■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	500	mA
Base current	I_B	50	mA
power dissipation	P_D	300	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

■ Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 50V, I_E = 0$			0.1	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = 5V, I_C = 0$			0.1	μA
DC current gain *	h_{FE}	$V_{CE} = 1V, I_C = 100mA$	70		240	
		$V_{CE} = 6V, I_C = 400mA$	25			
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_C = 100mA, I_B = 10mA$		0.1	0.25	V
Base emitter voltage *	V_{BE}	$V_{CE} = 1V, I_C = 100mA$		0.8	1.0	V
Output capacitance	C_{ob}	$V_{CE} = 6V, I_E = 0, f = 1MHz$		7		pF
Transition frequency	f_T	$V_{CE} = 6V, I_E = 20mA$		300		MHz

*. PW≤350μs,duty cycle≤2%